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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









# 60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE IntelliFET MOSFET

#### **Product Summary**

Continuous Drain Source Voltage: 60V

On-State Resistance: 500mΩ

Nominal Load Current (V<sub>IN</sub> = 5V): 1.3A

Clamping Energy: 90mJ

#### **Description**

The ZXMS6004FFQ is a self-protected low side IntelliFET™ MOSFET with logic level input. It integrates overtemperature, overcurrent, overvoltage (active clamp) and ESD protected logic level functionality. The ZXMS6004FFQ is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

#### **Applications**

- Especially Suited for Loads with a High In-Rush Current such as Lamps and Motors
- All Types of Resistive, Inductive and Capacitive Loads in Switching Applications
- μC Compatible Power Switch for 12V and 24V DC Applications
- Automotive Rated
- · Replaces Electromechanical Relays and Discrete Circuits
- Linear Mode Capability the current-limiting protection circuitry
  is designed to de-activate at low V<sub>DS</sub> to minimize on state power
  dissipation. The maximum DC operating current is therefore
  determined by the thermal capability of the package/board
  combination, rather than by the protection circuitry. This does not
  compromise the product's ability to self-protect at low V<sub>DS</sub>.

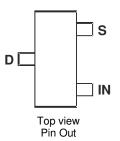
### Features and Benefits

- Compact High Power Dissipation Package
- Low Input Current
- Logic Level Input (3.3V and 5V)
- Short Circuit Protection with Auto Restart
- Overvoltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Overcurrent Protection
- Input Protection (ESD)
- High Continuous Current Rating
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: SOT23F
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 0.012 grams (Approximate)





#### **Ordering Information** (Note 5)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXMS6004FFQTA	1K6	7	12	3,000

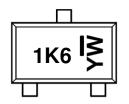
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q10x qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Document number: DS37132 Rev. 4 - 2

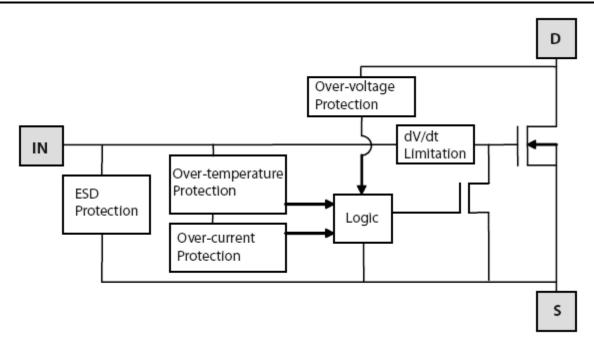


### **Marking Information**



Y: Year: 0~9
W: Week: A-Z: 1~26
a~z: 27~52
z: Represents 52 & 53 Week
1K6 = Product Type Marking Code

## **Functional Block Diagram**





# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Continuous Drain-Source Voltage	V <sub>DS</sub>	60	V
Drain-Source Voltage for Short Circuit Protection	V <sub>DS(SC)</sub>	36	V
Continuous Input Voltage	V <sub>IN</sub>	-0.5 +6	V
Continuous Input Current @-0.2V $\leq$ V <sub>IN</sub> $\leq$ 6V Continuous Input Current @V <sub>IN</sub> $<$ -0.2V or V <sub>IN</sub> $>$ 6V	I <sub>IN</sub>	No limit   I <sub>IN</sub>   ≤2	mA
Pulsed Drain Current @V <sub>IN</sub> = 3.3V	I <sub>DM</sub>	2	Α
Pulsed Drain Current @V <sub>IN</sub> = 5V	I <sub>DM</sub>	2.5	Α
Continuous Source Current (Body Diode)	Is	1	Α
Pulsed Source Current (Body Diode)	I <sub>SM</sub>	5	Α
Unclamped Single Pulse Inductive Energy, T <sub>J</sub> = +25°C, I <sub>D</sub> = 0.5A, V <sub>DD</sub> = 24V	Eas	90	mJ
Electrostatic Discharge (Human Body Model)	V <sub>ESD</sub>	4,000	V
Charged Device Model	V <sub>CDM</sub>	1,000	V

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Power Dissipation @T <sub>A</sub> = +25°C (Note 6) Linear Derating Factor	P <sub>D</sub>	0.83 6.66	W mW/°C
Power Dissipation @T <sub>A</sub> = +25°C (Note 7) Linear Derating Factor	P <sub>D</sub>	1.5 12.0	W mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	150	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	$R_{\theta JA}$	83	°C/W
Thermal Resistance, Junction to Case (Note 8)	Rejc	44	°C/W
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

- 6. For a device surface mounted on 15mm x 15mm single sided, 1oz weight copper on 1.6mm FR4 board, in still air conditions. 7. For a device surface mounted on 50mm x 50mm single sided, 2oz weight copper on 1.6mm FR4 board, in still air conditions. 8. Thermal resistance from junction and the mounting surfaces of the drain pins.

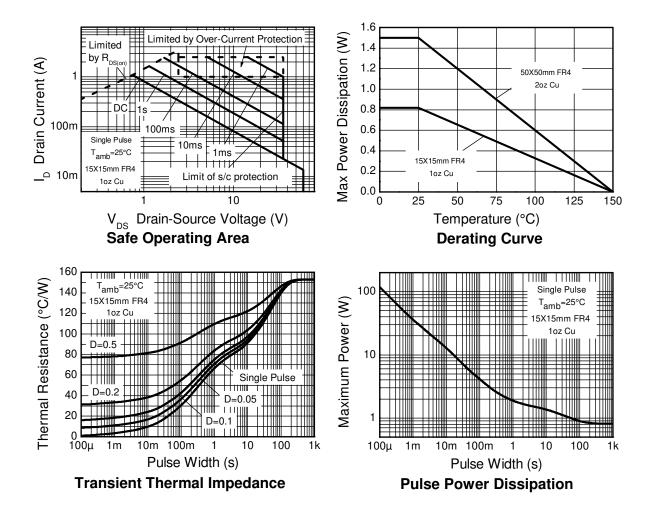
### **Recommended Operating Conditions**

The ZXMS6004FF is optimized for use with  $\mu C$  operating from 3.3V and 5V supplies.

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	$V_{IN}$	0	5.5	V
Ambient Temperature Range	T <sub>A</sub>	-40	+125	°C
High Level Input Voltage for MOSFET to be On	V <sub>IH</sub>	3	5.5	V
Low Level Input Voltage for MOSFET to be Off	V <sub>IL</sub>	0	0.7	V
Peripheral Supply Voltage (Voltage to which Load is Referred)	V <sub>P</sub>	0	36	V



### **Typical Thermal Characteristics**





# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Static Characteristics						
Drain-Source Clamp Voltage	$V_{DS(AZ)}$	60	65	70	V	$I_D = 10mA$
Off-State Drain Current			_	500	nA	$V_{DS} = 12V, V_{IN} = 0V$
On-State Drain Gurrent	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 36V, V_{IN} = 0V$
Input Threshold Voltage	V <sub>IN(TH)</sub>	0.7	1	1.5	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$
Input Current		_	60	100		$V_{IN} = +3V$
Imput Guirent	I <sub>IN</sub>	_	120	200	μA	$V_{IN} = +5V$
Input Current while Overtemperature Active	_	_	_	220	μΑ	$V_{IN} = +5V$
Static Drain-Source On-State Resistance	D	_	400	600	mΩ	$V_{IN} = +3V, I_D = 0.5A$
Static Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	_	350	500	11177	$V_{IN} = +5V, I_D = 0.5A$
Continuous Drain Current (Note 6)	- I <sub>D</sub>	0.9	_	_		$V_{IN} = 3V; T_A = +25^{\circ}C$
Continuous Drain Current (Note 6)		1.0	_	_	А	$V_{IN} = 5V; T_A = +25^{\circ}C$
Continuous Dunin Comment (Nata 7)		1.2	_	_		$V_{IN} = 3V; T_A = +25^{\circ}C$
Continuous Drain Current (Note 7)		1.3	_	_		$V_{IN} = 5V$ ; $T_A = +25$ °C
Current Limit (Note 0)	I <sub>D(LIM)</sub>	0.7	1.7	_	Α	$V_{IN} = +3V$
Current Limit (Note 9)		1	2.2	_		$V_{IN} = +5V$
Dynamic Characteristics						
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5	_		
Rise Time	$t_R$	_	10	_		V 10V I 0 FA V 5V
Turn-Off Delay Time	t <sub>D(OFF)</sub>		45	_	μs	$V_{DD} = 12V$ , $I_D = 0.5A$ , $V_{GS} = 5V$
Fall Time	fF	_	15	_		
Overtemperature Protection						
Thermal Overload Trip Temperature (Note 10)	$T_{JT}$	+150	+175		°C	_
Thermal Hysteresis (Note 10)	f <sub>F</sub>	_	+10	_	°C	_

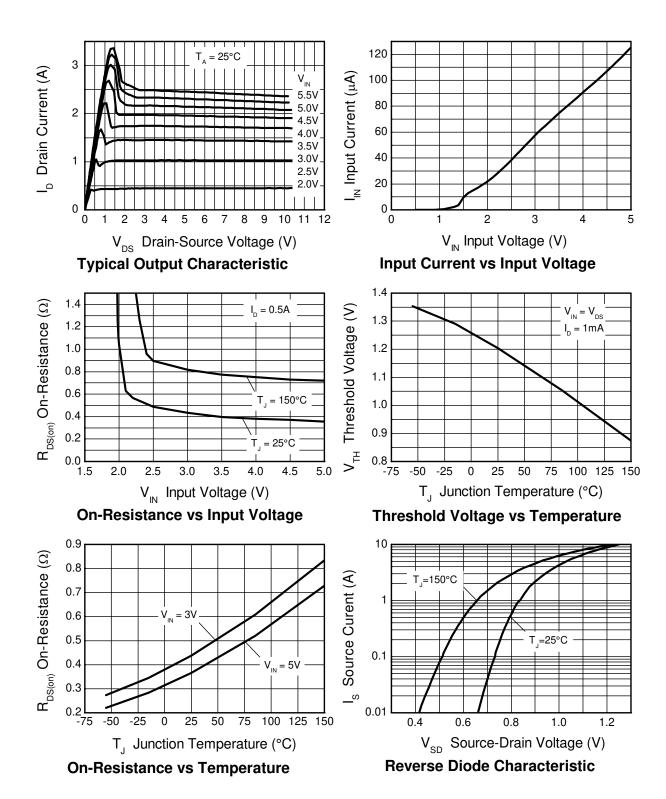
Notes:

The drain current is restricted only when the device is in saturation (see graph 'Typical Output Characteristic'). This allows the device to be used in the
fully on-state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside
saturation makes current limit unnecessary.

<sup>10.</sup> Overtemperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods.

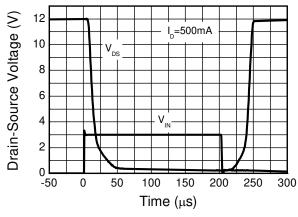


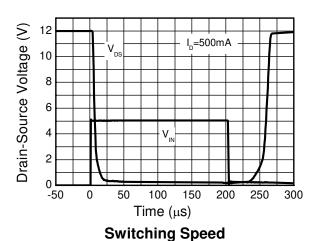
# **Typical Performance Characteristics**





# **Typical Performance Characteristics** (continued)





### **Switching Speed**

 $V_{\text{IN}} = 5V$  —  $V_{\text{IN}} = 5V$  —  $V_{\text{IN}} = 15V$  —  $V_{\text{DS}} = 15V$  —  $V_{\text{DS}} = 15V$  —  $V_{\text{DS}} = 100$  —  $V_{\text{D$ 

**Typical Short Circuit Protection** 

10 Time (ms)

5

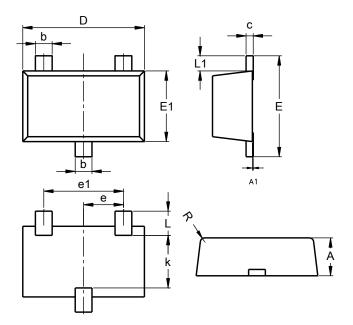
0.0

0



# **Package Outline Dimensions**

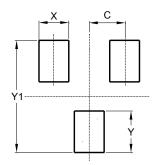
Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



SOT23F					
Dim	Min Max Typ				
Α	0.80	1.00	0.90		
b	0.35	0.50	0.44		
С	0.10	0.20	0.16		
D	2.80	3.00	2.90		
е	0.95 REF				
e1	(	0.190 RI	F		
Е	2.30	2.50	2.40		
E1	1.50	1.70	1.65		
k	1.20				
L	0.30	0.65	0.50		
L1	0.30	0.50	0.40		
R	0.05	0.15	-		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	0.95		
Х	0.80		
Y	1.110		
Y1	3.000		



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